

PLASTIC SILICON RECTIFIERS

REVERSE VOLTAGE - **50 to 1000** Volts
FORWARD CURRENT - **1.0** Ampere

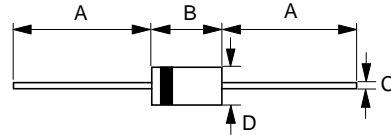
FEATURES

- Low cost
- Diffused junction
- Low forward voltage drop
- Low reverse leakage current
- High current capability
- The plastic material carries UL recognition 94V-0

MECHANICAL DATA

- Case : JEDEC DO-41 molded plastic
- Polarity : Color band denotes cathode
- Weight : 0.012 ounces, 0.34 grams
- Mounting position : Any

DO-41



DO-41		
Dim.	Min.	Max.
A	25.4	-
B	4.10	5.20
C	0.70 \varnothing	0.86 \varnothing
D	2.00 \varnothing	2.70 \varnothing
All Dimensions in millimeter		

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ $T_A=75^\circ\text{C}$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current 8.3ms single half sine-wave super imposed on rated load (JEDEC Method)	I_{FSM}	30							A
Maximum forward Voltage at 1.0A DC	V_F	1.0							V
Maximum DC Reverse Current @ $T_J=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_J=100^\circ\text{C}$	I_R	5 50							μA
Typical Junction Capacitance (Note 1)	C_J	15							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	26							$^\circ\text{C/W}$
Operating Temperature Range	T_J	-55 to +125							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150							$^\circ\text{C}$

NOTES : 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2. Thermal Resistance Junction to Ambient.

RATING AND CHARACTERISTIC CURVES
1N4001 thru 1N4007

